



**DMN2710UW** 

#### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> Max	I <sub>D</sub> Max T <sub>A</sub> = +25°C
201/	0.45Ω @ V <sub>GS</sub> = 4.5V	0.9A
20V	0.6Ω @ V <sub>GS</sub> = 2.5V	0.8A

#### **Description and Applications**

This MOSFET has been designed to minimize the on-state resistance (RDs(ON)) yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- General Purpose Interfacing Switch
- Power Management Functions
- DC-DC Converters
- Analog Switch

#### 20V N-CHANNEL ENHANCEMENT MODE MOSFET

#### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please <u>contact us</u> or your local Diodes representative. <u>https://www.diodes.com/quality/product-definitions/</u>

#### Mechanical Data

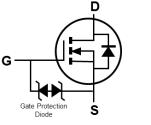
- Case: SOT323
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 (e3)
- Weight: 0.027 grams (Approximate)

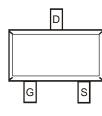




SOT323

Top View





Equivalent Circuit

Top View

#### Ordering Information (Note 4)

Part Number	Case	Packaging
DMN2710UW-7	SOT323	3,000/Tape & Reel
DMN2710UW-13	SOT323	10,000/Tape & Reel

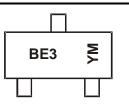
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

## **Marking Information**



 $\begin{array}{l} \text{BE3} = \text{Product Type Marking Code} \\ \text{YM} = \text{Date Code Marking} \\ \hline \hline Y = \text{Year (ex: H = 2020)} \\ \text{M} = \text{Month (ex: 9 = September)} \end{array}$ 

Date Code Key

Notes:

	0000	0004	0000	0000	0004	0005	0000	0007	0000	0000	0000	0004
Year	2020	2021	2022	2023	2024	2025	2026	2027	2028	2029	2030	2031
Code	н	1	J	K	L	М	N	0	Р	R	S	Т
									-	_		_
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec



### Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Drain-Source Voltage	Vdss	20	V	
Gate-Source Voltage		V <sub>GSS</sub>	±6	V
Continuous Drain Current (Note 6) $V_{GS}$ = 4.5V	ID	0.9 0.7	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle=1%)	ldм	5	A	
Maximum Body Diode Forward Current (Note 5)		ls	0.6	A

#### Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit	
Total Power Dissipation (Note 5)		PD	0.47	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	RθJA	268	°C/W
Total Power Dissipation (Note 6)		PD	0.6	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R <sub>0JA</sub>	212	°C/W
Operating and Storage Temperature Range		TJ, TSTG	-55 to +150	°C

# **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)						
Drain-Source Breakdown Voltage	BVDSS	20	—		V	V <sub>GS</sub> = 0V, I <sub>D</sub> = 250µA
Zero Gate Voltage Drain Current @Tc = +25	°C Idss	_	—	100	nA	V <sub>DS</sub> =20V, V <sub>GS</sub> = 0V
Gate-Source Leakage	IGSS	_	—	±1.0	μA	$V_{GS} = \pm 4.5 V, V_{DS} = 0 V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	VGS(TH)	0.5	—	1.0	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
			0.13	0.45		$V_{GS} = 4.5V, I_{D} = 600 \text{mA}$
Static Drain-Source On-Resistance	RDS(ON)		0.16	0.6	Ω	VGS = 2.5V, ID = 500mA
			0.22	0.75		$V_{GS} = 1.8V, I_D = 350mA$
Diode Forward Voltage	Vsd		0.7	1.2	V	VGS = 0V, IS = 150mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss		42	—	pF	
Output Capacitance	Coss		13	—	pF	$V_{DS} = 16V, V_{GS} = 0V$ f = 1.0MHz
Reverse Transfer Capacitance	Crss		6.5	—	pF	1 = 1.0MHZ
Total Gate Charge	Qg		0.6	—	nC	
Gate-Source Charge	Qgs		0.1		nC	$V_{GS} = 4.5V, V_{DS} = 10V,$
Gate-Drain Charge	Q <sub>gd</sub>		0.1	_	nC	I <sub>D</sub> = 250mA
Turn-On Delay Time	td(on)		4.9		ns	
Turn-On Rise Time Turn-Off Delay Time		_	3.1	_	ns	$V_{DD} = 10V, V_{GS} = 4.5V,$
			386		ns	$R_L = 47\Omega, R_g = 10\Omega$
Turn-Off Fall Time	tF	_	174	—	ns	$I_D = 200 \text{mA}$
Reverse Recovery Time	t <sub>RR</sub>	_	88		ns	I <sub>F</sub> = 1.0A, di/dt = 100A/µs
Reverse Recovery Charge	QRR	_	29	_	nC	IF = 1.0A, di/dt = 100A/µs

Notes:

Device mounted on FR-4 substrate PC board, with minimum recommended pad layout.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1inch square copper plate.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.



### **DMN2710UW**

2

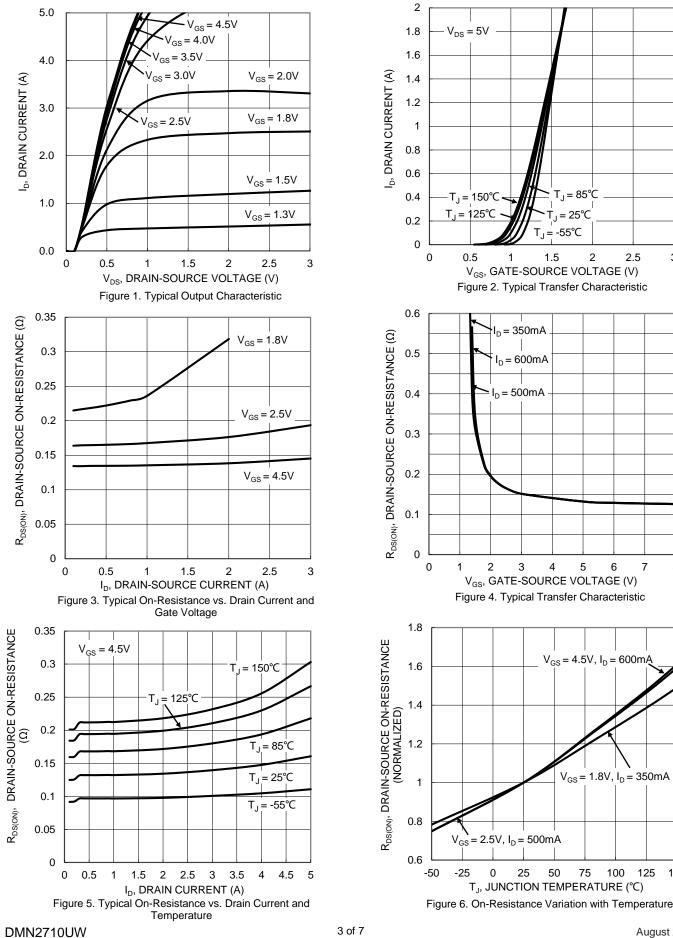
2.5

7

8

6

3



Document number: DS42640 Rev. 2 - 2

125

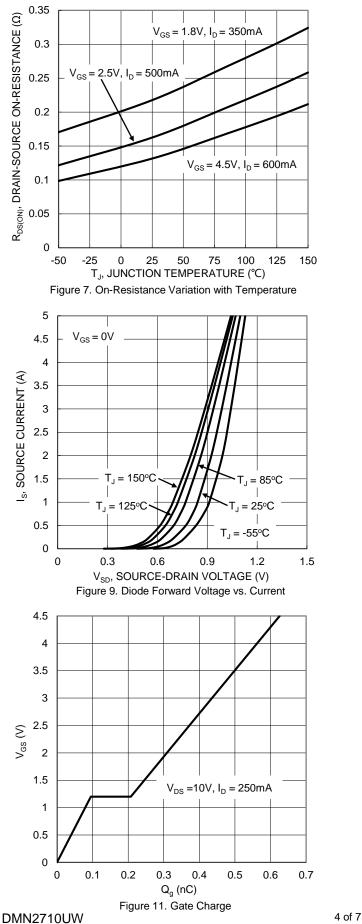
150

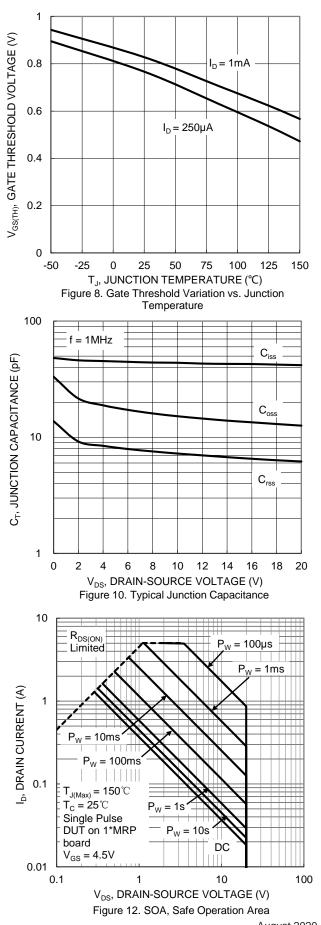
100

Downloaded From Oneyac.com



#### **DMN2710UW**



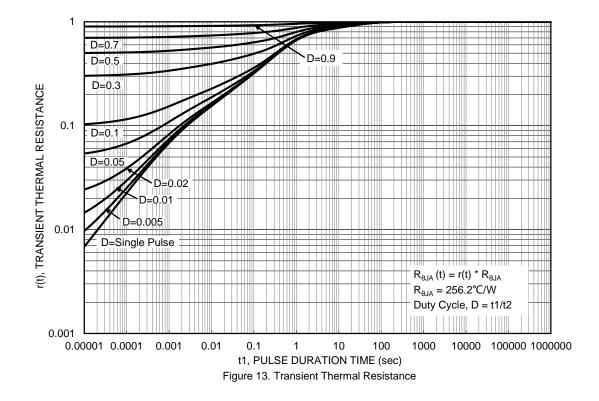


Document number: DS42640 Rev. 2 - 2

Downloaded From Oneyac.com

August 2020 © Diodes Incorporated



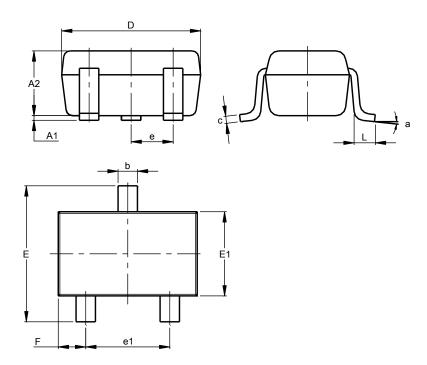




### **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

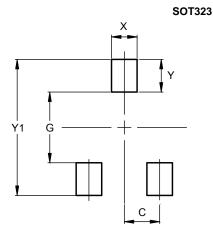




SOT323								
Dim	Min	Max	Тур					
A1	0.00	0.10	0.05					
A2	0.90	1.00	0.95					
b	0.25	0.40	0.30					
C	0.10	0.18	0.11					
D	1.80	2.20	2.15					
Е	2.00	2.20	2.10					
E1	1.15	1.35	1.30					
e	C	).650 B	SC					
e1	1.20	1.40	1.30					
F	0.375	0.475	0.425					
L	0.25	0.40	0.30					
а	0°	8°						
All	Dimen	sions i	in mm					

### **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	0.650
G	1.300
Х	0.470
Y	0.600
Y1	2.500

DMN2710UW Document number: DS42640 Rev. 2 - 2



#### IMPORTANT NOTICE

DIODES INCORPORATED MAKES NO WARRANTY OF ANY KIND, EXPRESS OR IMPLIED, WITH REGARDS TO THIS DOCUMENT, INCLUDING, BUT NOT LIMITED TO, THE IMPLIED WARRANTIES OF MERCHANTABILITY AND FITNESS FOR A PARTICULAR PURPOSE (AND THEIR EQUIVALENTS UNDER THE LAWS OF ANY JURISDICTION).

Diodes Incorporated and its subsidiaries reserve the right to make modifications, enhancements, improvements, corrections or other changes without further notice to this document and any product described herein. Diodes Incorporated does not assume any liability arising out of the application or use of this document or any product described herein; neither does Diodes Incorporated convey any license under its patent or trademark rights, nor the rights of others. Any Customer or user of this document or products described herein in such applications shall assume all risks of such use and will agree to hold Diodes Incorporated and all the companies whose products are represented on Diodes Incorporated website, harmless against all damages.

Diodes Incorporated does not warrant or accept any liability whatsoever in respect of any products purchased through unauthorized sales channel. Should Customers purchase or use Diodes Incorporated products for any unintended or unauthorized application, Customers shall indemnify and hold Diodes Incorporated and its representatives harmless against all claims, damages, expenses, and attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized application.

Products described herein may be covered by one or more United States, international or foreign patents pending. Product names and markings noted herein may also be covered by one or more United States, international or foreign trademarks.

This document is written in English but may be translated into multiple languages for reference. Only the English version of this document is the final and determinative format released by Diodes Incorporated.

#### LIFE SUPPORT

Diodes Incorporated products are specifically not authorized for use as critical components in life support devices or systems without the express written approval of the Chief Executive Officer of Diodes Incorporated. As used herein:

- A. Life support devices or systems are devices or systems which:
  - 1. are intended to implant into the body, or
  - 2. support or sustain life and whose failure to perform when properly used in accordance with instructions for use provided in the labeling can be reasonably expected to result in significant injury to the user.
- B. A critical component is any component in a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or to affect its safety or effectiveness.

Customers represent that they have all necessary expertise in the safety and regulatory ramifications of their life support devices or systems, and acknowledge and agree that they are solely responsible for all legal, regulatory and safety-related requirements concerning their products and any use of Diodes Incorporated products in such safety-critical, life support devices or systems, notwithstanding any devices- or systems-related information or support that may be provided by Diodes Incorporated. Further, Customers must fully indemnify Diodes Incorporated and its representatives against any damages arising out of the use of Diodes Incorporated products in such safety-critical, life support devices or systems.

Copyright © 2020, Diodes Incorporated

www.diodes.com

单击下面可查看定价,库存,交付和生命周期等信息

>>Diodes Incorporated(达迩科技(美台))